Study on Chemical Non-polar Solvent Heating by Microwave

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(Received: 6 March 2012;

Accepted: 19 November 2012)

AJC-12431

The choice of vessel is vital for heating non-polar solvent. In this paper, non-polar solvent at container with different vessel wall sizes and properties was heated indirectly by microwave. The uniformity of temperature was analyzed using COMSOL multiphysics under different vessel walls during microwave heating. The results show that the temperature uniformity was influenced by the different parameters of vessel wall sizes and properties and the uniformity of temperature can be highly improved by changing the thickness and property of vessel wall.

Key Words: Non-polar solvent, Microwave.

INTRODUCTION

Recent reports indicated that microwave could evidently accelerate reactions and the rate enhancement factor could reach over one thousand. Most chemical reactions are sensitive to temperature; therefore using microwaves to heat reactants presents an impressive application prospect^{1,2}. At present, in the reactions assisted and catalyzed, the majority of reaction solvents are polar in order that they are heated preferably. However, the non-polar solvents are also commonly used in a number of chemical reactions.

Although the dielectric properties of some sample are too poor to allow efficient heating by microwave radiation, the use of container that have large loss tangent values can significantly overcome this problem and enable adequate heating of the whole sample. This often provides an efficient way of using non-polar solvents for running chemical syntheses using microwave radiation. However, this method might cause heterogeneous temperature distribution in chemical syntheses. Thus, it is necessary to analyze some parameters influencing temperature uniformities using numerical calculation.

Due to the high microwave absorptive, with regard to SiC, materials (*i.e.* a solvent or a reaction mixture) contained inside the container will be effectively shielded from the electromagnetic field³. The heat flow through the walls of the reaction vessel and subsequent heat exchange with the reaction

mixture contained inside is exceptionally fast based on high thermal conductivity and diffusibility of SiC⁴.

According to the classification made by Kumbhar and Kulkarni⁵, the coupling of electromagnetic and thermal fields is weak, due to the large difference in the time constants of the two problems⁵. Thus it is necessary to consider the two problems, which are the results of the electric field analysis allowing the determination of the source term for the heat diffusion equation and the analysis of the temperature distribution in the load enabling a re-evaluation of the physical constants (permittivity, loss angle, *etc.*), which in turn will modify the electric field distribution⁶. The electric energy is transformed into thermal energy and thermal energy will affect the temperature distribution. COMSOL can solve effectively the coupled electrothermal problem and it is chosen finally for this research.

EXPERIMENTAL

In this paper, the COMSOL software based on FEM is used to analyze the uniformity of temperature. The models with different vessel wall sizes and properties are separately presented to measure in detail the uniformity of temperature in the non-solvent. The physical model is shown in Fig. 1.

The problem to be solved consists of a 188 mm × 267 mm × 270 mm metallic rectangular applicator. In this model, the inside material is non-polar carbon tetrachloride and the outer is vessel wall (such as SiC). The cubage of CCl₄ is V_{CCl_4}

Fig. 1. Physical model

$= \pi * r^2 * h$ and the cubage of SiC is $V_{SiC} = \pi * R^2 * h - \pi * r^2 * h$. R is the radius of big cylinder, r is the radius of small cylinder and h is the height of CCl_4 and SiC.

The permittivity of CCl_4 was taken from reference⁷, which is $\epsilon_r = 2.24 - j * 0.002$. The permittivity of silicon carbide changes with temperatures, so it is necessary to establish a function between the permittivity and temperature. From⁴, the relation between $\tan \delta$ and temperature is shown (Fig. 2).

Fig. 2. $\tan \delta$ as a function of temperature for the SiC

The values of four special points from the curve of silicon carbide are analyzed in Table-1.

TABLE-1 LOSS $\tan \delta$ FROM THE SiC CURVE				
T (°C)	50	100	150	200
Tan (δ)	0.18	0.33	0.60	0.69

According to the definition of loss tangent, $\tan \delta$ is imaginary part dividing real part of the permittivity. It is assumed that $\epsilon_r = a - j * b$, so $\tan \delta = b/a$. The real part of SiC permittivity, which is obtained from literature is $a = 6.52$ and its imaginary part, which is obtained by linear fit (Table-1) is $b = -6.40786 + 0.02347 * T$. Finally, the permittivity of SiC is $\epsilon_r = 6.52 - j * (-6.40786 + 0.02347 * T)$. During all the computational process, the input power is $P = 700$ W. The microwave heating time is $t = 5$ s. Relative parameters which are used to solve the case are listed in Table-2.

TABLE-2 RELATIVE PARAMETERS		
Parameter	SiC	CCl_4
Heat conduction: k (w/m*K)	20	0.106
Density: ρ (kg/m ³)	3200	1595
Atmospheric heat capacity: C_p [J/(kg* °C)]	170	854

After calculation, the results such as maximum and minimum value of temperature were recorded during heating. Then the uniformities of temperature were obtained respectively by formula (1). The average temperature was achieved by formula (2).

Finally, comparing the results, the uniformity of temperature is gained.

$$\text{Temperature uniformity} = \sqrt{\frac{T_{\max} - T_{\min}}{T_{\max}}} \quad (1)$$

where, $T_{\max}$ is the maximum temperature and $T_{\min}$ is minimum temperature.

$$\text{Average temperature} = \frac{\sum_{i=1}^{\infty} T_i}{V} \quad (2)$$

where, T_i is the temperature for every grid of heated materials.

RESULTS AND DISCUSSION

The models with different vessel wall sizes and properties were calculated and the following research reports in detail their results during heating.

According to simulation results, the maximum and minimum value of the temperature were recorded during the microwave heating process. Finally, the uniformity of the temperature were calculated by the formula (1) and (2). The results from different vessel wall sizes and properties for the temperature are listed in Tables 3 and 4.

TABLE-3 RESULTS OF THE TEMPERATURE DISTRIBUTION UNDER DIFFERENT VESSEL WALL SIZES				
Thickness of vessel wall: d (m)	$T_{\max}$ (K)	$T_{\min}$ (K)	Average temperature: T_{avg} (K/m ³)	Temperature uniformity
0.005 m	342.201	297.368	319.256	0.362
0.010 m	326.366	299.240	312.654	0.288
0.020 m	312.138	299.792	305.982	0.199
0.040 m	306.806	302.275	304.858	0.122

TABLE-4 RESULTS OF THE TEMPERATURE DISTRIBUTION UNDER DIFFERENT VESSEL WALL PROPERTIES				
Dielectric vessel wall	$T_{\max}$ (K)	$T_{\min}$ (K)	Average temperature: T_{avg} (K/m ³)	Temperature uniformity
Without Dielectric vessel wall	567.321	90.110	328.458	0.917
One kind of dielectric vessel wall	314.758	300.494	307.635	0.213
Two kinds of dielectric vessel wall	369.195	70.029	219.597	0.900
Four kinds of dielectric vessel wall	308.719	301.871	305.751	0.149

By comparing the data in Tables 3 and 4, one can observed that the effect of heating solvent is desired using different vessel wall material and sizes and especially when the thickness of vessel wall is 0.04 m or the vessel wall is made of four kinds of dielectric vessel wall, the maximum is almost equal to minimum and the temperature uniformity is lowest and the effect of heating solvent is best. From above, it is obvious that the temperature uniformities were influenced by size of vessel wall, the uniformity of temperature can be highly improved by changing the thickness and property of vessel wall.

Conclusion

By calculation and analysis, the configurations with different thickness and property of walls are integrally compared in the uniformity of temperature field. When the temperature uniformity of non-polar solvent is not obvious during microwave heating, it can improve significantly the uniformity of temperature by changing the thickness and property of vessel wall.

ACKNOWLEDGEMENTS

This project was supported by National Science Foundation of China (No. 61001019) and Sichuan Province Science supported planning project of China (2011GZ0222).

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